

RD130m | SD 3.01 | microSD Card

SMART's RD130m microSD Cards are fully SD compliant. Offered in commercial and industrial temperature versions based on 32nm and 24nm SLC Flash technologies, the RD130m microSD Cards are specifically designed to meet strict industrial operating and environmental requirements.

SMART's RD130m microSD Cards comply with SD v3.01 Standard with performance up to 68MB/s read and 50MB/s write. Incorporating onboard error detection and correction algorithms, and static and dynamic wear-leveling techniques, SMART's microSD Memory Cards ensure years of reliable operation over a product's life.



Features & Benefits

- Capacities:
 - 4GB (SDHC)
 - 1GB, 2GB (SDSC)
- SLC NAND Flash
- Low Power Dissipation
- Onboard Wear-Leveling
- RoHS Compliant

Applications

- Embedded Computing
- Industrial Meters and Industrial Control
- Medical Equipment
- Networking
- Telecom and Communications

Product Family Overview

Form Factor	Capacity	Sequential Performance
SD 3.01 microSD Card (SDHC)	4GB	Up to 68MB/s Read
	46B	Up to 50MB/s Write
SD 2 01 minrs SD Cord (SDSC)	C) 1GB, 2GB	Up to 23MB/s Read
SD 3.01 microSD Card (SDSC)		Up to 22MB/s Write

Specifications

	RD130m SD 3.01 microSD Card	
NAND Type	SLC	
Performance		
Sequential Read (maximum)	SD 3.01	
Sequential Read (maximum)	Up to 68MB/s (4GB)	
	Up to 23MB/s (1GB, 2GB)	
Convential Write (maximum)	Up to 50MB/s (4GB)	
Sequential Write (maximum)	Up to 22MB/s (1GB, 2GB)	
Reliability		
MTBF	> 3,000,000	
Endurance	4GB: 234TBW	
	2GB: 117TBW	
(Sequential Workload) ¹	1GB: 58TBW	
Power		
Vcc	2.7 - 3.6 V	
Environmental		
Operating Temperature	Extended: -25°C to +85°C	
	Industrial: -40°C to +85°C	
Storage Temperature	-40°C to +85°C	
Humidity	25% to 95%	
Physical		
Length	15 mm	
Width	11 mm	
Height	0.7/1.0 mm	

Ordering Information

Part Number	Density	
RD130m SD 3.01 microSD Card Extended Operating Temperature (-25°C to +85°C)		
SS9UD004GPHE8SE32	4GB	
SS9UD002GPHE8SE32	2GB	
SS9UD001GPHE8SE32	1GB	
RD130m SD 3.01 microSD Card Industrial Operating Temperature (-40°C to +85°C)		
SS9UD004GPHE8SI32	4GB	
SS9UD002GPHE8SI32	2GB	
SS9UD001GPHE8SI32	1GB	

¹Endurance is directly related to 128k sequential write workload



For more information, please visit: www.smartm.com

*Product images are for promotional purposes only. Labels may not be representative of the actual product.

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